

VHF VARIABLE CAPACITANCE DIODE

The BB620 is a VHF variable capacitance diode in planar technology with a very high capacitance ratio intended for VHF-band A up to 160 MHz in all-band tuners. The diode is encapsulated in a hermetically sealed SOD123 envelope suitable for surface mounting.

QUICK REFERENCE DATA

Continuous reverse voltage	V_R	max.	30 V
Reverse current at $V_R = 30$ V	I_R	max.	10 nA
Diode capacitance at $f = 1$ MHz at $V_R = 28$ V	C_d		2.9 to 3.4 pF
Capacitance ratio at $f = 1$ MHz	$\frac{C_d (V_R = 1 \text{ V})}{C_d (V_R = 28 \text{ V})}$		19.5 to 25
Series resistance at $f = 100$ MHz V_R is that value at which $C_d = 30$ pF	r_s	typ.	1.3 Ω

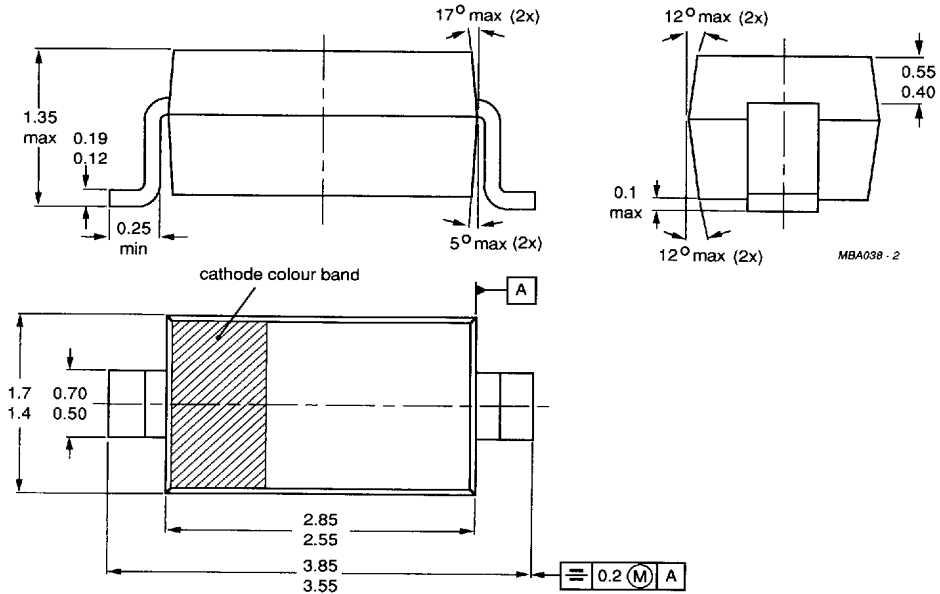
MECHANICAL DATA

Fig.1 SOD123.

Dimensions in mm

Marking code

BB620 = P



Cathode indicated by a red band.

RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Continuous reverse voltage	V_R	max.	30 V
Reverse voltage (peak value)	V_{RM}	max.	30 V
Forward current (DC)	I_F	max.	20 mA
Storage temperature range	T_{stg}		-55 to + 150 °C
Operating ambient temperature range	T_{amb}		-55 to + 125 °C

CHARACTERISTICS $T_{amb} = 25$ °C unless otherwise specified

Reverse current

$V_R = 30$ V

I_R max. 10 nA

$V_R = 30$ V; $T_{amb} = 85$ °C

I_R max. 200 nA

Reverse breakdown voltage

$I_R = 10$ μ A

$V_{(BR)R}$ min. 30 V

Diode capacitance at $f = 1$ MHz

$V_R = 1$ V

C_d 62 to 76 pF

$V_R = 28$ V

C_d 2.9 to 3.4 pF

Capacitance ratio at $f = 1$ MHz

$\frac{C_d (V_R = 1 \text{ V})}{C_d (V_R = 28 \text{ V})}$ 19.5 to 25

Tolerance of the capacitance difference between two diodes of $V_R = 1.0$ V to 28 V

$\frac{\Delta C}{C}$ max. 2.5 %

Series resistance

at $f = 100$ MHz and at that value of V_R at which $C_d = 30$ pF

r_s typ. 1.3 Ω

Series inductance

L_s typ. 2.8 nH